10/677,311

FORM PTO 1449 (*modified*)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

October 3, 2003

ATTY DOCKET NO.	APPLICATION NO.
03500.016340.1	~~UNASSIGNED~~ (Cont. of 10/112,748)
APPLICANT: FUMIHIRO INUI	
FILING DATE: October 3, 2003	GROUP: 2818 ~~Unassigned~~

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
JM		5,831,920	11/03/98	Chen, et al.	365	225.5	
JM		5,699,293	12/06/97	Tehrani, et al.	365	158	
JM		5,640,343	06/1997	Gallagher, et al.	365	171	
JM		6,055,178	04/2000	Naji	365	158	
JM		6,504,752	01/2003	Ito	365	158	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)

JM		Magneto-Resistive IC Memory Limitations and Architecture Implications, Roy E. Scheu rlein (pages 47 to 50), 1998 Int'l. Nonvolatile Memory Technology Conference.
JM		Spin-Valve-Like Ferromagnetic Tunnel Junction, Kazuo Kobayashi, et al. (Pages 11 to 17) (with English translation), November 5, 1999.

EXAMINER: SON MAI — DATE CONSIDERED: 07-15-04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Sheet 1 of 1

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